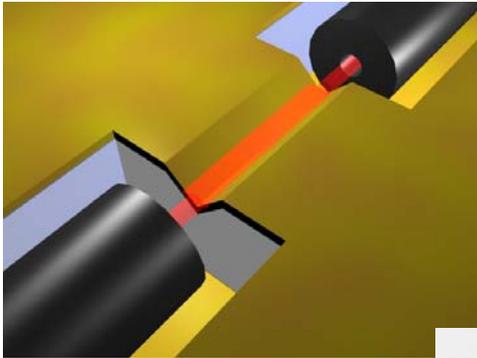


Plasmon confinement in V-groove waveguides fabricated by Nanolmprint Lithography



Irene Fernandez-Cuesta, Xavier Borrissé and Francesc Pérez-Murano



Rasmus Bundgaard Nielsen, Alexandra Boltasseva, and Anders Kristensen



COM-DTU

Dominique Heinis and Niek van Hulst



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Outlook

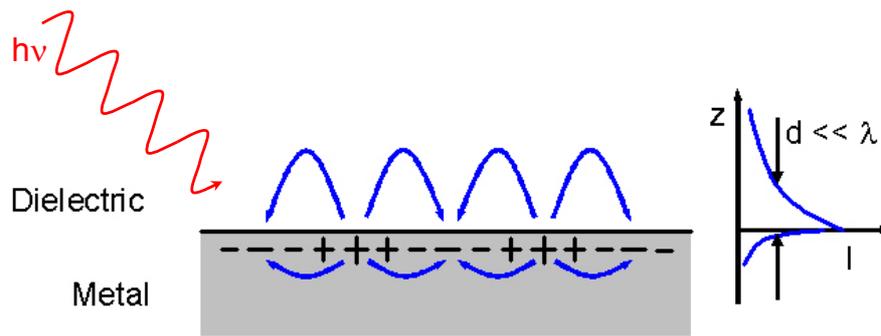
- Plasmons: definition, confinement in V-gr., simulations, state of the art
- V-grooves fabrication process: design, description and results
 - Stamp
 - Nanoimprint and post processing
- Optical characterization
 - Far field
 - Near Field
- Conclusions



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SURFACE PLASMON POLARITONS - SPPs



- PLASMON (SPP): Quasi-particles resulting from the coupling of free electrons in a metal and the electromagnetic field of the light.
 - SPPs are evanescent waves, propagating along the dielectric/metal interface.
- Propagation length ~10 - 400 μm (depending on the wavelength of the incident light).
- > Plasmons: suitable for guiding light in sub- λ structures -> nanostructures (waveguides)

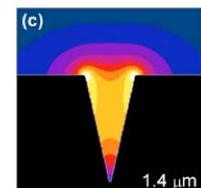
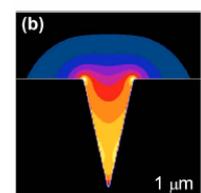
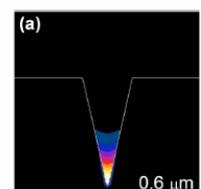
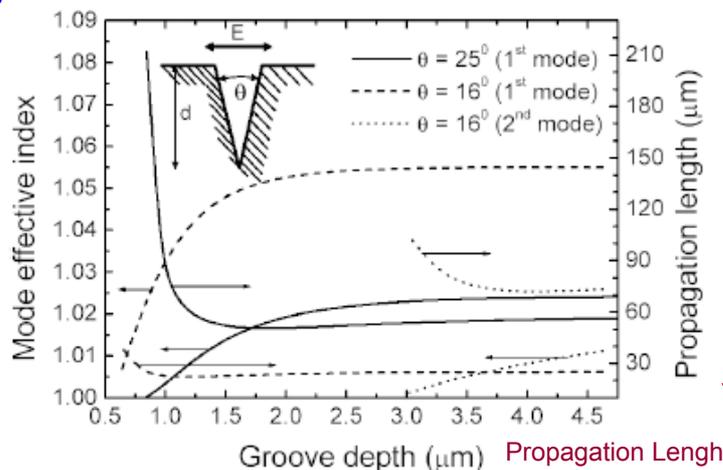


Surface Plasmon Polariton in sub- λ structures:

Channel-Plasmon-Polaritons (CPPs)

V-Groove: SPPs propagating in each side couple at the bottom of the groove.

V-GROOVE



Propagation Length is reduced for decreasing V angle

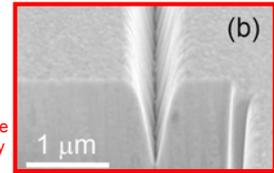


State of the art: First experimental results in v-grooves

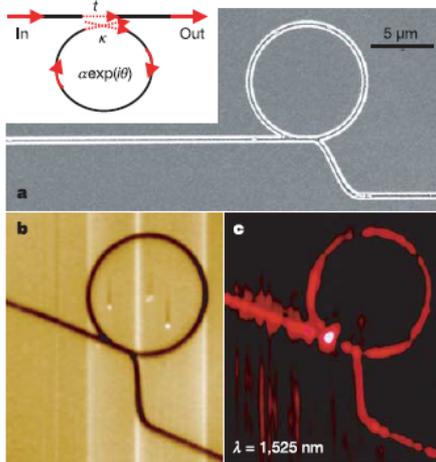
SNOM measurements in v-shape structures

S. I. Bozhevolnyi, V. S. Volkov, E. Devaux, J.Y. Laluet, and T. W. Ebbesen, Nature 440, 508 (2006)

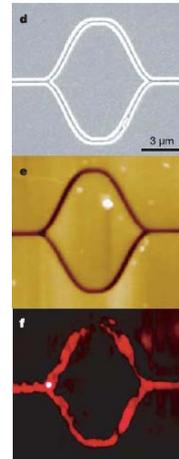
Silver
V-Groove
made by
FIB



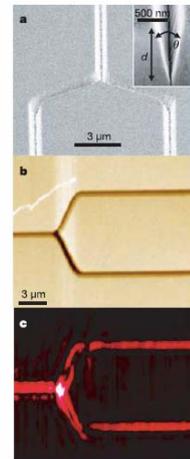
RING RESONATORS



MACH ZENDER INTERFEROMETER



Y-SPLITTER



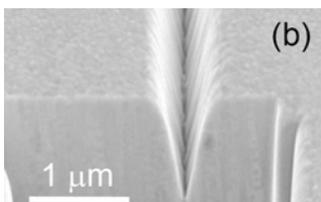
It is possible to confine and guide light in sub- λ structures



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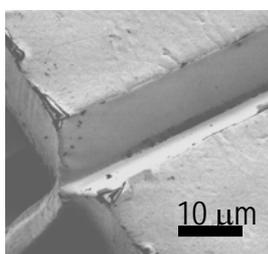
Disadvantage: FIB fabrication is suitable just for demonstrators



- Sharp grooves, but it is difficult to control the angle
- Rough sidewalls
- Slow, process in serie
- A bigger area has to be milled, for light coupling

Not suitable for fabrication of devices, or "real" applications

Our proposal: v-grooves fabrication process based in Nanoimprint lithography



Fabrication: Nanoimprint + postprocessing

- Process in parallel: up to 180 grooves in one single wafer!!
- The smoothness is improved

Can be used to fabricate devices



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Design and NIL-based fabrication process



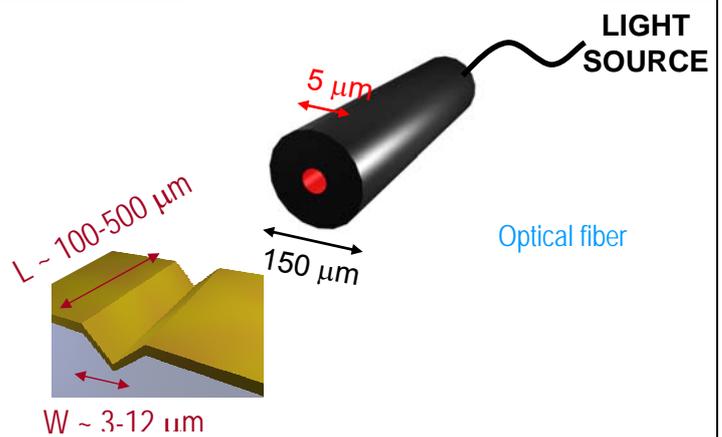
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V-groove device design

Wafer scale fabrication: different lengths and sizes in the same sample.

V-Groove: variable length (100-500 μm) and width (3-12 μm), angle = 70° , (fix by the fabrication process)

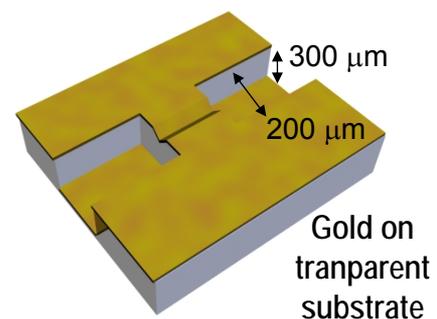


NIL allows multilevel fabrication in the same step:

Integration of v-groove and deep channels

Channels: deep (300 μm) and wide (200 μm), to approach the fibers to the groove

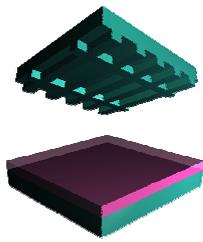
OUTPUT



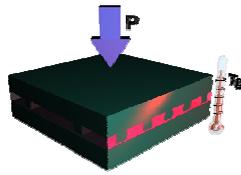
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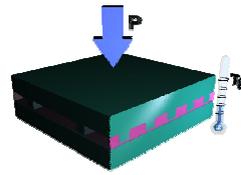
NanoImprinting



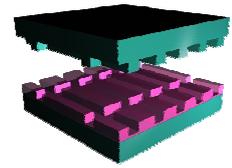
1. Hard stamp
2. Substrate with a polymer layer



3. Heat,
4. Pressure



5. Cool down
(with the pressure)

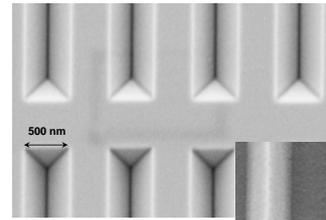


6. Separate

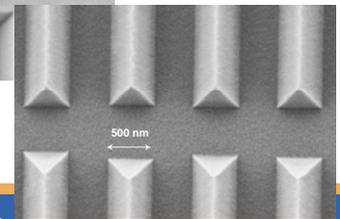
Main advantages:

- ✓ Unlimited resolution (given by the stamp fabrication)
- ✓ Parallel fabrication process: 1 sample processing at a time, containing several single chips
- ✓ Simple and cheap process, suitable for large scale fabrication of devices

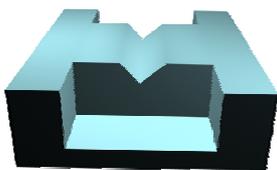
Silicon Stamp



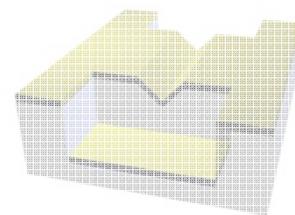
Imprint in PMMA



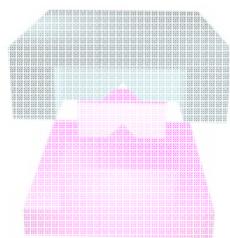
A. Stamp



C. Final Structures



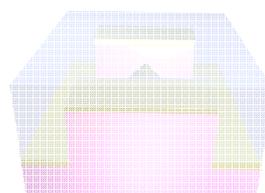
B. Nanoimprint and postprocessing



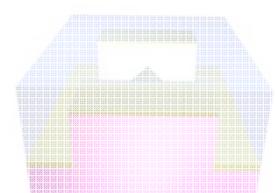
1. Imprint in PMMA



2. Gold deposition



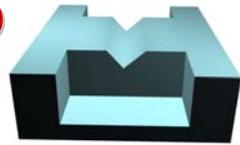
3. Ormcomp
deposition (UV curing)



4. Removing PMMA

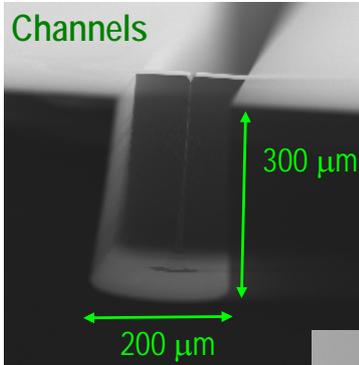


Silicon Stamp

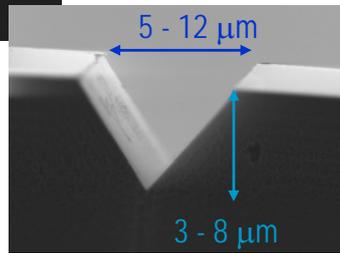


1. RIE

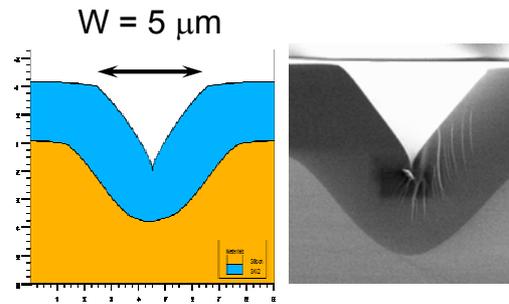
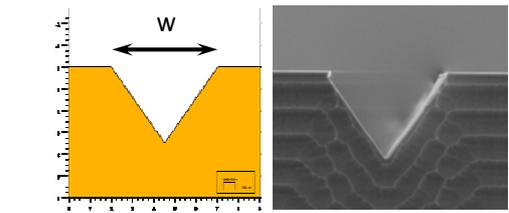
Channels



2. KOH V-Grooves

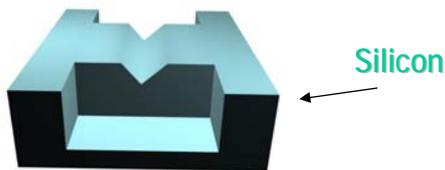


3. Oxidation

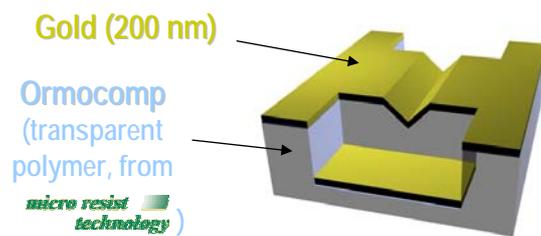


6h, 1150°C

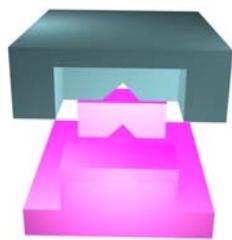
A. Stamp



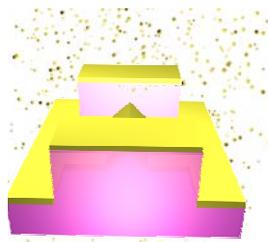
C. Final Structures



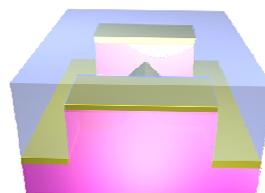
B. Nanoimprint and postprocessing



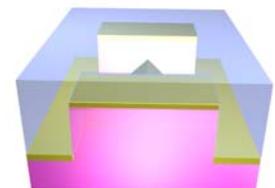
1. Imprint in PMMA



2. Gold deposition

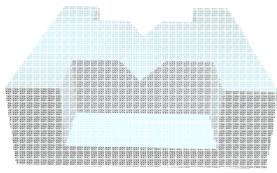


3. Ormocomp deposition (UV curing)

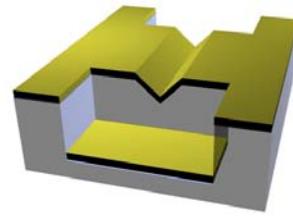


4. Removing PMMA

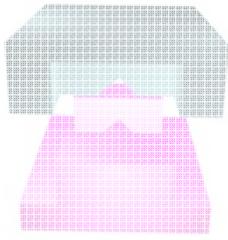
A. Stamp



C. Final Structures



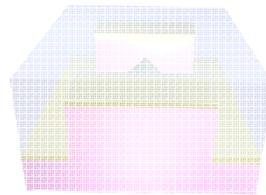
B. Nanoimprint and postprocessing



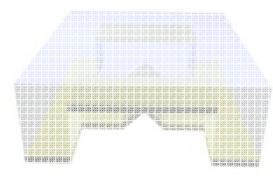
1. Imprint in PMMA



2. Gold deposition



3. Ormcomp deposition (UV curing)



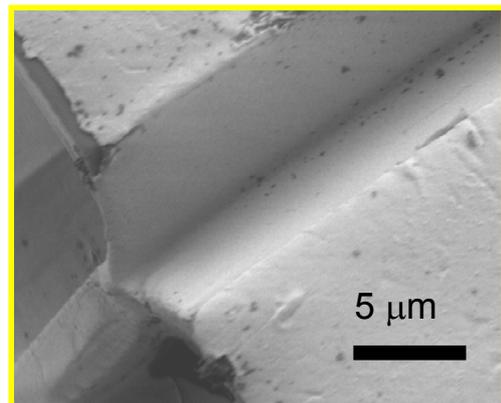
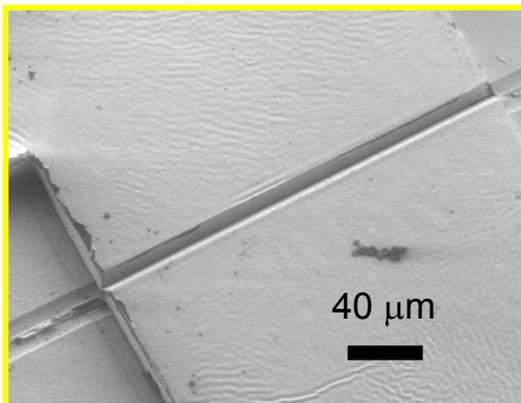
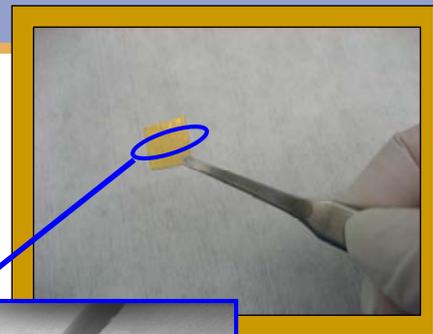
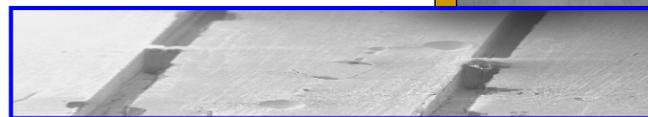
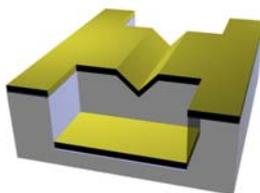
4. Removing PMMA



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Gold Grooves on transparent substrate



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OPTICAL CHARACTERIZATIONS

I. Far field images

II. Near field: SNOM
characterization



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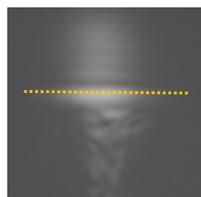
Far field characterization



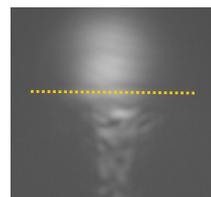
1. Fiber Output (blank)



2. Sample surface



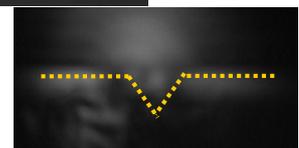
Polarization TM



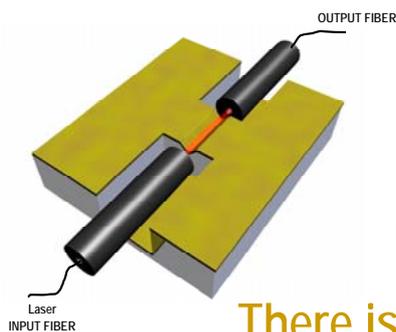
Polarization TE

3. Output of the groove (V)

Polarization TM



Polarization TE



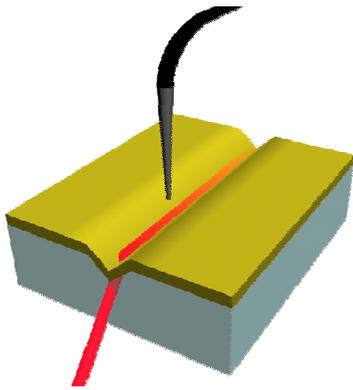
There is a clear output mode for TM polarization



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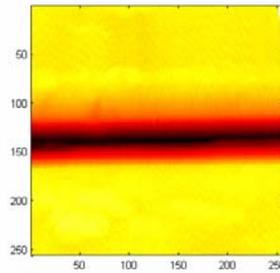
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Optical Near Field characterization (SNOM)

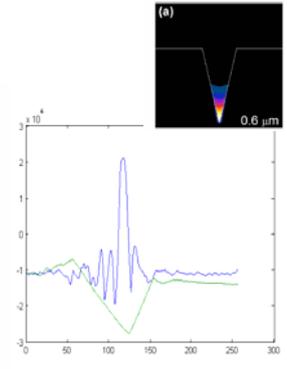
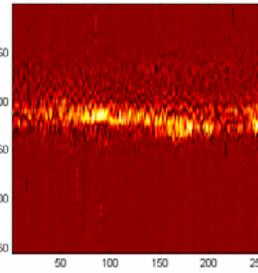


RED LIGHT

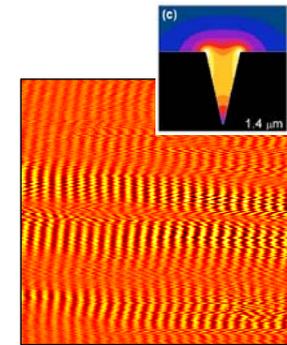
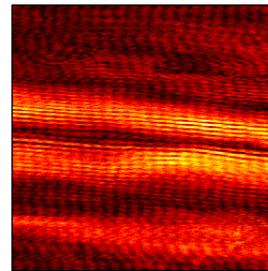
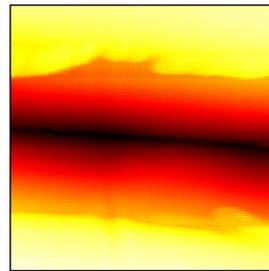
Topography



Intensity



IR LIGHT



Light couples and propagates inside the grooves

Topography

Intensity

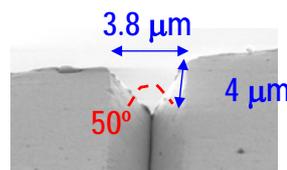
Phase



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Evaluation of the performance for light guiding



V-groove geometry:

- width = 3.8 μm
- depth = 4 μm
- apex angle = 50°

SNOM measurements (at $\lambda \cong 1525 \text{ nm}$):

- Propagation length = 120 μm
- Confinement: FWHM = 1.33 μm

- CPPs are **less confined** than in previous works (FIB), due to the large apex angle.
- This results in **larger propagation lengths** -> good compromise between confinement and losses.

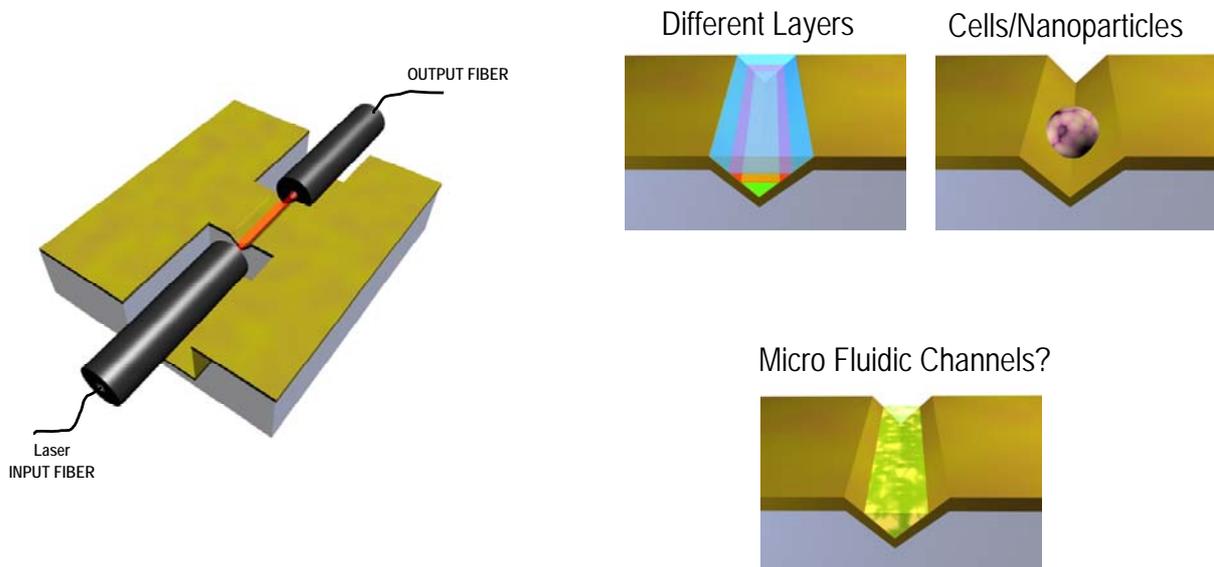


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Use for (bio)sensing: Fiber-to-fiber measurements

Change in the output signal as a function of the media inside the V-waveguide.



Conclusions

- ❑ Plasmon confinement in v-grooves has been demonstrated recently.
- ❑ A method for parallel fabrication of v-grooves integrated with deep channels, in wafer scale, has been presented.
- ❑ Optical characterization in far field show an output mode for TM polarization
- ❑ SNOM measurements show plasmon confinement and light guiding in the waveguides.